PATENT ASSIGNMENT COVER SHEET

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EPAS ID: PAT6071190

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
MARK I. GARDNER	03/16/2020
H. JIM FULFORD	04/18/2020
JEFFREY SMITH	03/16/2020
LARS LIEBMANN	03/16/2020
DANIEL CHANEMOUGAME	03/16/2020

RECEIVING PARTY DATA

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PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	16854340

CORRESPONDENCE DATA

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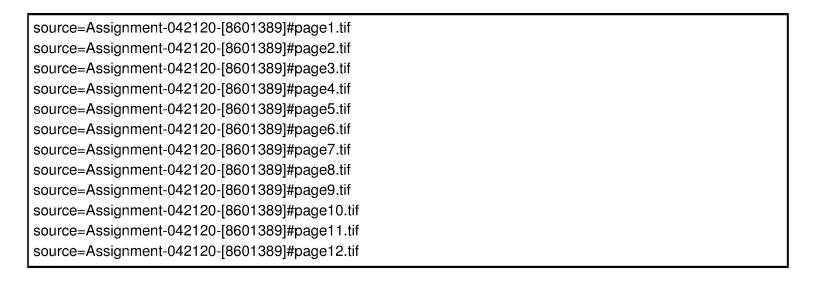
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ATTORNEY DOCKET NUMBER:	527302US
NAME OF SUBMITTER:	MATTHEW KORSEN
SIGNATURE:	/Matthew Korsen/
DATE SIGNED:	04/21/2020
	This document serves as an Oath/Declaration (37 CFR 1.63).
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Total Attachments: 12

PATENT REEL: 052454 FRAME: 0867

506024475



PATENT REEL: 052454 FRAME: 0868

DECLARATION (37 CFR 1.63) AND ASSIGNMENT FOR NONPROVISIONAL UTILITY OR DESIGN PATENT APPLICATION

Title of Invention: METHOD FOR FABRICATION OF HIGH DENSITY LOGIC AND MEMORY FOR ADVANCED CIRCUIT ARCHITECTURE

As a below named inventor, I hereby declare that:

This declaration and assignment is directed to:

The attached application having a	docket number and	title identified	above, or
United States application number of	or PCT international	application n	umber
	filed on		

The above-identified application was made or authorized to be made by me.

I believe that I am the original inventor or an original joint inventor of a claimed invention in the above-identified application.

I have reviewed and understand the contents of the above-identified application, including the claims.

I am aware of the duty to disclose to the United States Patent and Trademark Office all information known to me to be material to patentability as defined in 37 C.F.R. § 1.56.

I hereby acknowledge that any willful false statement made in this Declaration is punishable under 18 U.S.C. 1001 by fine or imprisonment of not more than five (5) years, or both.

Assignor(s): The Assignor(s) is/are the undersigned inventor(s). The inventor(s) named below has/have made certain inventions, improvements, and/or discoveries (herein referred to as the "Invention") disclosed in the above-identified patent application.

Assignee: The Assignee is Tokyo Electron Limited, a corporation of Japan having a place of business at Tokyo, Japan (herein referred to as the "ASSIGNEE"). The term "ASSIGNEE" used herein includes successors, legal representatives, and assigns of the ASSIGNEE. The ASSIGNEE desires to acquire the entire worldwide right, title, and interest in and to the Invention and in and to any and all patent applications and patents obtained from the Invention.

(1) Legal name of Inventor:	Mark I. GARDNER
Inventor's Signature:	West & Gard-Date: 3/16/202
Residence City/State/Country:	Cedar Creek, TX, United States
Mailing Address:	c/o NanoFab 300 South, 255 Fuller Road, Suite 214, Albany, NY 12203
Citizenship:	United States
(2) Legal name of Inventor:	H. Jim FULFORD
Inventor's Signature:	Date:
Residence City/State/Country:	Marianna, FL, United States
Mailing Address:	c/o NanoFab 300 South, 255 Fuller Road, Suite 214, Albany, NY 12203
Citizenship:	United States
(3) Legal name of Inventor:	Jeffrey SMITH
Inventor's Signature:	Date:
Residence City/State/Country:	Clifton Park, NY, United States
Mailing Address:	c/o NanoFab 300 South, 255 Fuller Road, Suite 214, Albany, NY 12203
Citizenship:	United States

(4) Legal name of Inventor:	Lars LIEBMANN
Inventor's Signature:	Date:
Residence City/State/Country:	Mechanicville, NY, United States
Mailing Address:	c/o NanoFab 300 South, 255 Fuller Road, Suite 214, Albany, NY 12203
Citizenship:	United States
(5) Legal name of inventor: Inventor's Signature:	Daniel CHANEMOUGAME Date: 03/16/2020
Residence City/State/Country:	Niskayuna, NY, United States
Mailing Address:	c/o NanoFab 300 South, 255 Fuller Road, Suite 214, Albany, NY 12203
Citizenship:	United States

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Citizenship:	United States
(2) Legal name of Inventor:	H. Jim/FULFORD
Inventor's Signature:	3. his sub 1 Date: 4/18/2020
Residence City/State/Country:	Marianna, FL, United States
Mailing Address:	c/o NanoFab 300 South, 255 Fuller Road, Suite 214, Albany, NY 12203
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Citizenship:	United States
(3) Legal name of Inventor:	Jeffrey SMITH
Inventor's Signature:	Jeffrey T Smith Date: 16 March 2020
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Citizenship:	United States

Atty. Docket No. 527302US

(4) Legal name of Inventor:	Lars LIEBMANN
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Atty. Docket No. 527302US

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